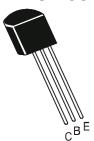


Continental Device India Limited

An ISO/TS16949 and ISO 9001 Certified Company



PNP SILICON PLANAR EPITAXIAL TRANSISTORS



BC 307, A, B, C BC 308, A, B, C BC 309, A, B, C

TO-92 Plastic Package

General Purpose Transistors Deisgned For Small Signal Amplification

From DC To Low Radio Frequencies

ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	BC307	BC308	BC309	UNITS
Collector Emitter Voltage	V_{CEO}	45	25	25	V
Collector Base Voltage	V_{CBO}	50	30	30	V
Emitter Base Voltage	V_{EBO}	5	5	5	V
Collector Current Continuous	I _C		100		mA
Power Dissipation@ Ta=25°C	P_{D}		350		mW
Derate Above 25°C			2.8		mW/°C
Power Dissipation@ Tc=25°C	P_{D}		1		W
Derate Above 25°C			8		mW/°C
Operating And Storage Junction	T_{j},T_{stg}		-55 to +150		°C
Temperature Range					
THERMAL RESISTANCE					
Junction to ambient	$R_{th(j-a)}$		357		°C/W
Junction to case	$R_{th(j-c)}$		125		°C/W

PNP SILICON PLANAR EPITAXIAL TRANSISTORS

C_BE

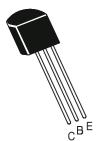
BC 307, A, B, C BC 308, A, B, C BC 309, A, B, C

TO-92 Plastic Packa: e

ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)								
	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS		
Collector Emitter Breakdown	BV_CEO	$I_C=2mA,I_B=0$						
Voltage								
BC307			45			V		
BC308, BC309			25			V		
Emitter Base Breakdown Voltage	BV_{EBO}	I _E =100uA, I _C =0	5			V		
Collector Emitter Leakage Current								
BC307	I_{CES}	$V_{CES} = 50V, V_{BE} = 0$			15	nA		
BC308, BC309		V_{CES} =30V, V_{BE} =0			15	nA		
BC307		$V_{CES} = 50V$, $V_{BE} = 0$,			4	μΑ		
		$T_A = 125^{\circ}C$				·		
BC308, BC309		$V_{CES} = 30V, V_{BE} = 0,$			4	μΑ		
,		$T_A = 125^{\circ}C$				•		
DC Current Gain		1 _A = 120 0						
A	h_{FE}	$I_C=10uA, V_{CF}=5V$		90				
В	''FE	10-100/1, V CE-0 V		150				
C				270				
BC307, BC308, BC309		$I_C=2mA, V_{CF}=5V$	120	210	800			
A		10-2111/1, V CE-0 V	120	170	220			
В			200	290	460			
C			420	500	800			
			.20	000	000			
Α		$I_C=2mA, V_{CF}=5V^*$		120				
В		0 , 02		180				
С				300				
Collector Emitter Saturation	V _{CE} (sat)	$I_C=10\text{mA}, I_B=0.5\text{mA}$		0.10	0.3	V		
Voltage	OL()	$I_C=100\text{mA}, I_B=5\text{mA}$		0.25	- · -	V		
Base Emitter Saturation Voltage	V _{p∈} (sat)	$I_C=10\text{mA}, I_B=0.5\text{mA}$		0.7		V		
	DE ()	$I_C=100\text{mA}, I_B=5\text{mA}$		1.0		V		
Base Emitter On Voltage	V _{BE} (on)	$I_C=2mA, V_{CE}=5V$	0.55	0.62	0.7	V		

SILICON PLANAR EPITAXIAL TRANSISTORS



BC 307, A, B, C BC 308, A, B, C BC 309, A, B, C

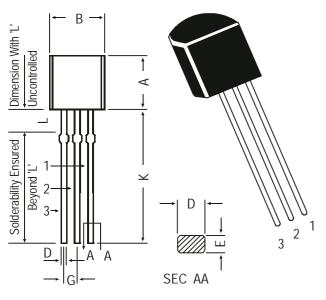
TO-92 Plastic Package

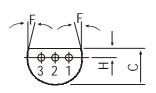
ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
DYNAMIC CHARACTERISTICS						
Transition Frequency	f_T	I _C =10mA, V _{CE} =5V				
BC307	7	f=50MHz		280		MHz
BC308	3			320		MHz
BC309)			360		MHz
Collector Base Capacitance	C_cbo	V _{CB} =10V, I _E =0			6	pF
Noise Figure		f=1MHz				
BC 309) NF	I_C =0.2mA, V_{CE} =5V Rg=2K Ω f=30Hz to 15KHz		2	4	dB
BC307, BC308	3	f =1KHz, B=200Hz		2	10	dB
BC309)			2	4	dB
		R_S =2 $K\Omega$ f=30 Hz				
		to 15KHz				

TO-92 Plastic Package

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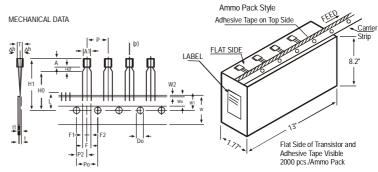
PIN CONFIGURATION

- 1. EMITTER
- 2. BASE
- 3. COLLECTOR

DIM	MIN.	MAX.			
А	4.32	5.33			
В	4.45	5.20			
С	3.18	4.19			
D	0.41	0.55 0.50			
Е	0.35				
F	5 D	EG			
G	1.14	1.40			
Н	1.14	1.53			
K	12.70	_			
L	1.982	2.082			

All diminsions in mm.

TO-92 Transistors on Tape and Ammo Pack



All dimensions in mm unless specified otherwise

ITEM		SPECIFICATION					
ITEM	SYMBOL	MIN. NOM. MAX. TOL.		TOL .	REMARKS		
BODY WIDTH	A1	4.0		4.8			
BODY HEIGHT	Α	4.8		5.2			
BODY THICKNESS	Ţ	3.9		4.2			
PITCH OF COMPONENT	Р		12.7		±1		
FEED HOLE PITCH	Po		12.7		±0.3	CUMULATIVE PITCH ERROR 1.0 mm/20 PITCH	
FEED HOLE CENTRE TO	D0		/ 25				
COMPONENT CENTRE	P2		6.35		±0.4	TO BE MEASURED AT BOTTOM OF CLINCH	
DISTANCE BETWEEN OUTER	_				+0.6		
LEADS	F		5.08		-0.2	47 TOD OF DODY	
COMPONENT ALIGNMENT	Δh		0 18	1	۸.	AT TOP OF BODY	
TAPE WIDTH HOLD-DOWN TAPE WIDTH	W Wo		18 6		±0.5 +0.2		
HOLE POSITION	W1		9		±0.2 +0.7		
HOLE POSITION	VVI		9		-0.5		
HOLD-DOWN TAPE POSITION	W2		0.5		±0.2		
LEAD WIRE CLINCH HEIGHT	Но		16		±0.5		
COMPONENT HEIGHT	H1			23.25			
LENGTH OF SNIPPED LEADS	L			11.0			
FEED HOLE DIAMETER	Do		4	١	±0.2		
TOTAL TAPE THICKNESS	t		2.54	1.2	١.,	t1 0.3 - 0.6	
LEAD - TO - LEAD DISTANCEF1,	F2		2.54		+0.4 -0.1		
CLINCH HEIGHT	H2			3			
PULL - OUT FORCE	(P)	6N					

- NOTES
 1. MAXIMUM ALIGNMENT DEVIATION BETWEEN LEADS NOT TO BE GREATER THAN 0.2 mm.
- MAXIMUM NON-CUMULATIVE VARIATION BETWEEN TAPE FEED HOLES SHALL NOT EXCEED 1 mm IN 20 PITCHES.

 HOLDDOWN TAPE NOT TO EXCEED BEYOND THE EDGE(S) OF CARRIER TAPE AND THERE SHALL BE NO EXPOSURE OF ADHESIVE.

 HOLDDOWN TAPE NOT TO EXCEED BEYOND THE EDGE(S) OF CARRIER TAPE AND THERE SHALL BE NO EXPOSURE OF ADHESIVE.

- A. NO MORE THAN 3 CONSECUTIVE MISSING COMPONENTS ARE PERMITTED.
 A TAPE TRAILER, HAVING AT LEAST THREE FEED HOLES ARE REQUIRED AFTER THE LAST COMPONENT.
 SPLICES SHALL NOT INTERFERE WITH THE SPROCKET FEED HOLES.

Packing Detail

1 doking botan										
PACKAGE	STANDARD PACK		INNER CARTO	N BOX	OUTER CARTON BOX					
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt			
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs			
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs			

Notes

BC 307, A, B, C BC 308, A, B, C BC 309, A, B, C

TO-92 Plastic Package

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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